

Dehydrogenation of ethane over gallium oxide in the presence of carbon dioxide

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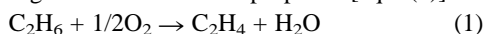
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Gallium oxide is found to be an effective catalyst for the dehydrogenation of ethane to ethene in the presence of carbon dioxide at 650 °C, giving 18.6% ethene yield with a selectivity of 94.5%.

Ethene is predominantly produced by steam cracking of naphtha, ethane or liquid petroleum gas at high temperatures at short residence time.

In order to reduce energy consumption of ethene production, oxidative dehydrogenation of ethane is proposed [eqn. (1)].



The reaction becomes exothermic and thermodynamically could be possible at relatively low temperatures. However, it is necessary to remove heat from the reaction and to avoid over oxidation to CO₂ to give high selectivity towards ethene. Recently, a great variety of catalysts have been developed and tested for this reaction.^{1–3} In the oxidative dehydrogenation of propane, Burch and Crabb⁴ pointed out that thermal non-catalytic oxidative cracking of propane proceeded to give propene in the same yield as compared to catalyzed runs which were operated about 50 °C lower than that of non-catalyzed runs. This suggests that catalyzed oxidative dehydrogenation of lower alkanes is not highly superior to thermal oxidative pyrolysis.

Recently, several attempts have been made to use carbon dioxide as an oxidant for coupling of methane,⁵ dehydrogenation of ethylbenzene⁶ or propane.⁷ However, the role of CO₂ in these reactions is still not clear. In addition, the effects of CO₂ on the conversion and yield of the product are not significant.

Here, we study the dehydrogenation of ethane to ethene over several metal oxide catalysts, and we have found that CO₂ markedly promoted dehydrogenation of ethane over Ga₂O₃ catalyst.

The catalysts used were commercially available MgO, Al₂O₃, SiO₂, CaO, TiO₂, V₂O₅, Cr₂O₃, Mn₃O₄, Fe₃O₄, ZnO, Ga₂O₃, Y₂O₃, ZrO₂, Nb₂O₅, MoO₃, In₂O₃, SnO₂, La₂O₃, CeO₂, Ta₂O₅ and Ti₂O₃. The reaction was carried out with a fixed-bed flow type quartz reactor (i.d. 10 × 350 mm) at atmospheric pressure. Using 200 mg of a catalyst, 5 ml min⁻¹ of C₂H₆ and 25 ml min⁻¹ of CO₂ were introduced. The runs were conducted for 30 min and products were analyzed by gas chromatography.

Fig. 1 shows ethene yields on the various metal oxide catalysts. Thermal dehydrogenation occurred to give only 2.3% of ethene yield. Equilibrium conversion of ethane to ethene is ca. 50% at 650 °C at a C₂H₆-Ar (or CO₂) ratio of 1 : 5. MgO, CaO, SiO₂, Ta₂O₅, Al₂O₃, SnO₂, MoO₃, and Ti₂O₃ did not show any catalytic activity while CeO₂, Nb₂O₅, Fe₃O₄, and ZrO₂ exhibited only slight catalytic activity. The order of the activity of oxides at the reaction temperature of 650 °C was as follows: Ga₂O₃ > Cr₂O₃ > V₂O₅ > TiO₂ > Mn₃O₄ > In₂O₃ > ZnO > La₂O₃. The C₂H₄ selectivities in all the metal oxide catalysts were > 85% in the dehydrogenation of ethane in the presence of CO₂. As expected, Cr₂O₃ and V₂O₅ exhibited high activities. These catalysts are known to be active catalysts for dehydrogenation of alkanes. Ga₂O₃ afforded the highest yield of ethene

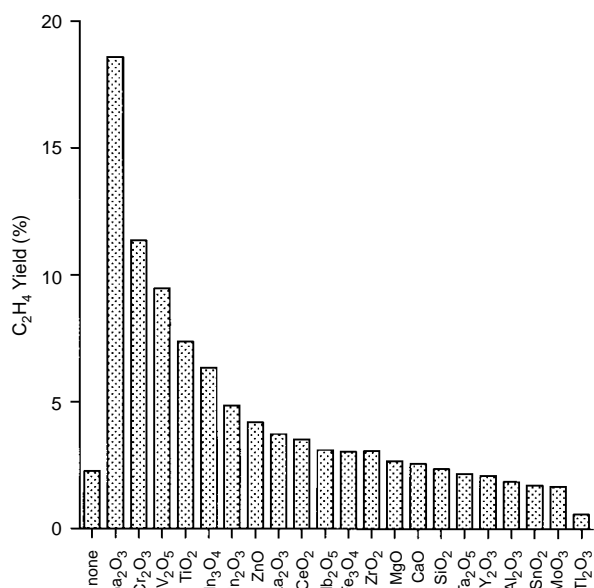


Fig. 1 Dehydrogenation of C₂H₆ in the presence of CO₂. Catalyst 200 mg; temperature: 650 °C; C₂H₆:CO₂ = 5:25 ml min⁻¹; SV = 9000 h⁻¹ ml (g cat)⁻¹.

(18.6%) amongst the various metal oxide catalysts. However, little work has dealt with Ga₂O₃ catalyst in the dehydrogenation of propane.⁸

Table 1 lists ethene yields on Ga₂O₃, Cr₂O₃, and V₂O₅ catalysts in the presence and absence of CO₂. The activity of the Ga₂O₃ catalyst in the presence of CO₂ was twice that in the absence of CO₂. Dehydrogenation of C₂H₆ in the presence of CO₂ over Ga₂O₃ catalyst produced mainly C₂H₄, CO, H₂ and H₂O. The yield of ethene with the Cr₂O₃ catalyst in the presence of CO₂ was slightly higher as compared to the run in Ar. The promoting effect of CO₂ in the dehydrogenation of C₃H₈ on Cr₂O₃/SiO₂ has been reported,⁵ but the increase in the propene yield was only 2.6% at 550 °C. On the other hand, the effect of

Table 1 Dehydrogenation of ethane in the presence of carbon dioxide^a

Catalyst	Surface area/ m ² g ⁻¹	Conv. (%) C ₂ H ₆	Yield (%) C ₂ H ₄	Selectivity (%)		
				C ₂ H ₄	CH ₄	C ₃ H ₈
Ga ₂ O ₃ (CO ₂)	9.8	19.6	18.6	95.0	3.8	1.0
Ga ₂ O ₃ (Ar)	9.8	9.6	9.0	94.0	5.0	0.7
Cr ₂ O ₃ (CO ₂)	2.8	12.1	11.4	93.8	5.8	0.4
Cr ₂ O ₃ (Ar)	2.8	10.4	10.2	97.6	1.8	0.6
V ₂ O ₅ (CO ₂)	3.5	9.8	9.5	97.1	2.9	—
V ₂ O ₅ (Ar)	3.5	12.5	11.5	91.7	7.4	0.9

^a Reaction conditions: 650 °C, SV = 9000 h⁻¹ ml (g cat)⁻¹. Composition of the feed gas; C₂H₆:CO₂(Ar) = 5:25 ml min⁻¹.

CO₂ on the yield of ethane with V₂O₅ in the presence of CO₂ was slightly detrimental. CO₂ promoted dehydrogenation of ethane exclusively over Ga₂O₃ catalyst. To our knowledge, such a marked promotion effect of CO₂ in a hydrocarbon conversion process has never been previously observed. The role of CO₂ in dehydrogenation of C₂H₆ over Ga₂O₃ catalyst is, as yet, unclear. With CO₂ considerable amounts of CO and H₂O were formed during the reaction, indicating reaction of CO₂ with H₂. The amount of H₂O was 1.09 mmol and that of CO was 1.07 mmol at 650 °C after 0.5 h. Dehydrogenation of C₂H₆ was strongly inhibited when Ga₂O₃ was impregnated onto a basic oxide such as MgO or La₂O₃. Another characteristic feature in the reaction in CO₂ is the increase in the yield of CH₄. From these findings the role of CO₂ may be as follows: slightly acidic CO₂ may strongly adsorb onto basic sites of gallium oxide, and as a result, the acidity of Ga₂O₃ would be enhanced. This possibility is reinforced by the fact that after dehydrogenation a certain amount of carbon was formed on the catalyst (Ga₂O₃, Cr₂O₃, and V₂O₅). Dehydrogenation of ethane would be catalyzed by acid sites on Ga₂O₃.

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